BAS11; BAS12

FEATURES

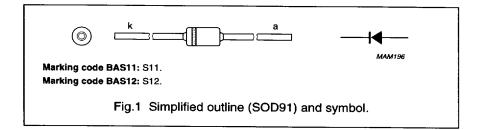
- · Glass passivated
- High maximum operating temperature
- Low leakage current
- · Excellent stability
- · Available in ammo-pack.

DESCRIPTION

Rectifier diodes in cavity free cylindrical SOD91 glass packages, incorporating Implotec^{™(1)} technology.

(1) Implotec is a trademark of Philips.

These packages are hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage				
	BAS11		_	300	l _v
	BAS12		_	400	V
V _{RWM}	working reverse voltage				
	BAS11		_	300	V
	BAS12		_	400	V
V _R	continuous reverse voltage			-,	
	BAS11		_	300	v
	BAS12		_	400	v
I _{F(AV)}	average forward current	averaged over any 20 ms period; T _{tp} = 75 °C; lead length = 10 mm; see Figs 2 and 4	-	350	mA
		averaged over any 20 ms period; T _{amb} = 30 °C; PCB mounting (see Fig.8); see Figs 3 and 4	_	300	mA
I _{FSM}	non-repetitive peak forward current	t = 10 ms half sinewave; T _j = T _{j max} prior to surge; V _R = V _{RRMmax}	_	4	Α
P _{RRM}	repetitive peak reverse power dissipation	t = 10 μs square wave; f = 50 Hz; T _{amb} = 25 °C	_	75	w
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-65	+150	°C

FOR REPLACEMENT TYPE SEE INDEX SECTION OF HANDBOOK SC01

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ELECTRICAL CHARACTERISTICS

 $T_j = 25$ °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	forward voltage	$I_F = 300 \text{ mA}$; $T_j = T_{jmax}$; see Fig.5	_	-	1.0	V
	_	I _F = 300 mA; see Fig.5	_	_	1.1	V
V _{(BR)R}	reverse avalanche breakdown voltage	I _R = 0.1 mA				
	BAS11		330	_	_	V
	BAS12		440	_	_	v
I _R	reverse current	V _R = V _{RRMmax} ; see Fig.6	-	_	250	nA
		V _R = V _{RRMmax} ; T _j = 125 °C; see Fig.6	_		10	μА
t _{rr}	reverse recovery time	when switched from $I_F = 0.5$ A to $I_R = 1$ A; measured at $I_R = 0.25$ A; see Fig.9	_	_	1	μs
C _d	diode capacitance	V _R = 0 V; f = 1 MHz; see Fig.7	_	20	_	pF

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point	lead length = 10 mm	180	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	340	K/W

Note

1. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper ≥40 μm, see Fig.8. For more information please refer to the "General Part of Handbook SC01".

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GRAPHICAL DATA

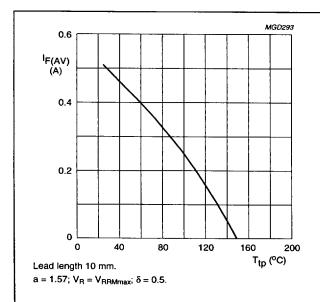


Fig.2 Maximum permissible average forward current as a function of tie-point temperature (including losses due to reverse leakage).

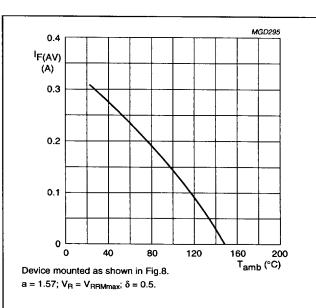
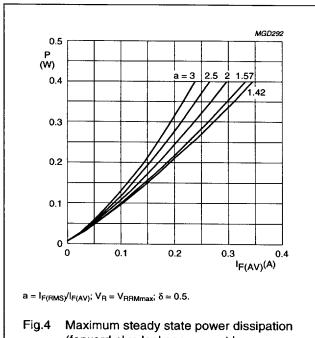
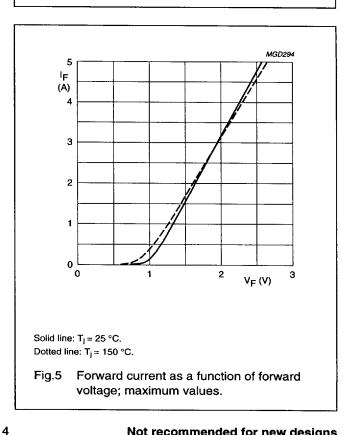


Fig.3 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).



(forward plus leakage current losses, excluding switching losses) as a function of average forward current.

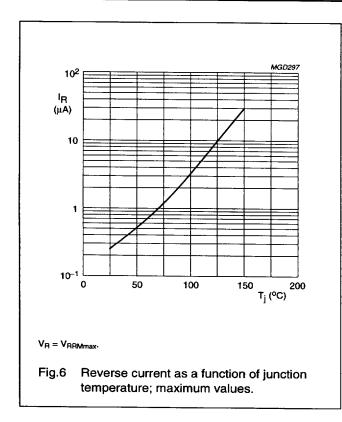


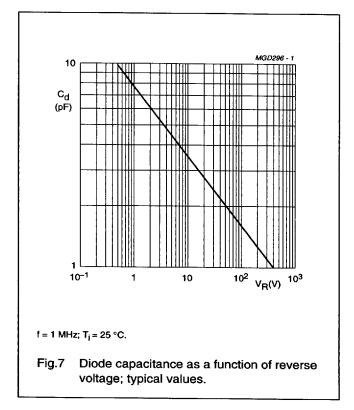
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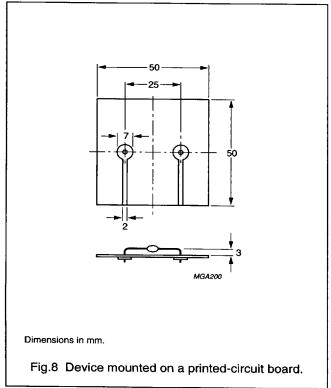
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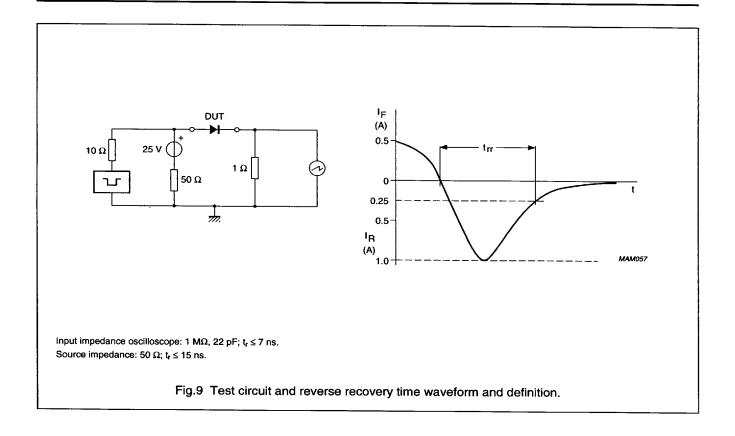
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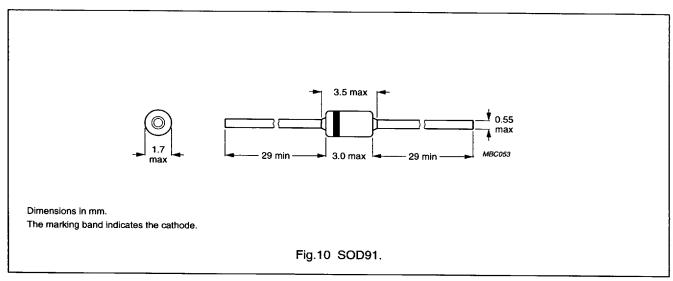
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PACKAGE OUTLINE



DEFINITIONS

Data sheet status		
Objective specification	This data sheet contains target or goal specifications for product development.	
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.	
Product specification	This data sheet contains final product specifications.	
Limiting values		
more of the limiting values of the device at these or at	n accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or may cause permanent damage to the device. These are stress ratings only and operation any other conditions above those given in the Characteristics sections of the specification limiting values for extended periods may affect device reliability.	
Application information		
Where application informat	tion is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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